

ISL21010

Micropower Voltage Reference

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The **ISL21010** is a precision, low dropout micropower bandgap voltage reference in a space-saving SOT-23 package. It operates from a single 2.2V to 5.5V supply (minimum voltage is dependent on voltage option) and provides a $\pm 0.2\%$ accurate reference. The ISL21010 provides up to 25mA output current sourcing with low 150mV dropout voltage.

Output voltage options include 1.024V, 1.2V, 1.5V, 2.048V, 2.5V, 3.0V, 3.3V, and 4.096V. The low supply current and low dropout voltage combined with high accuracy make the ISL21010 ideal for precision battery powered applications.

Applications

- Battery management/monitoring
- Low power standby voltages
- Portable instrumentation
- Consumer/medical electronics
- Lower cost industrial and instrumentation
- Power regulation circuits
- Control loops and compensation networks
- LED/diode supply

Features

- Reference output voltages 1.024V, 1.25V, 1.5V, 2.048V, 2.5V, 3.0V, 3.3V, 4.096V
- Precision 0.2% initial accuracy
- Input voltage range:
 - ISL21010-10, -12, -15 -20 2.2V to 5.5V
 - ISL21010-25 2.6V to 5.5V
 - ISL21010-30 3.1V to 5.5V
 - ISL21010-33 3.4V to 5.5V
 - ISL21010-41 4.2V to 5.5V
- Output current source capability 25mA
- Operating temperature range -40°C to +125°C
- Output voltage noise ($V_{OUT} = 2.048V$) 58 μ V_{P-P} (0.1Hz to 10Hz)
- Supply current 48 μ A (typical)
- Tempco 50ppm/°C
- Package 3 Ld SOT-23
- Pb-free (RoHS compliant)

Related Literature

For a full list of related documents, visit our website

[ISL21010DFH310](#), [ISL21010DFH312](#), [ISL21010CFH315](#), [ISL21010CFH320](#), [ISL21010CFH325](#), [ISL21010CFH330](#), [ISL21010CFH333](#), [ISL21010CFH341](#) product page

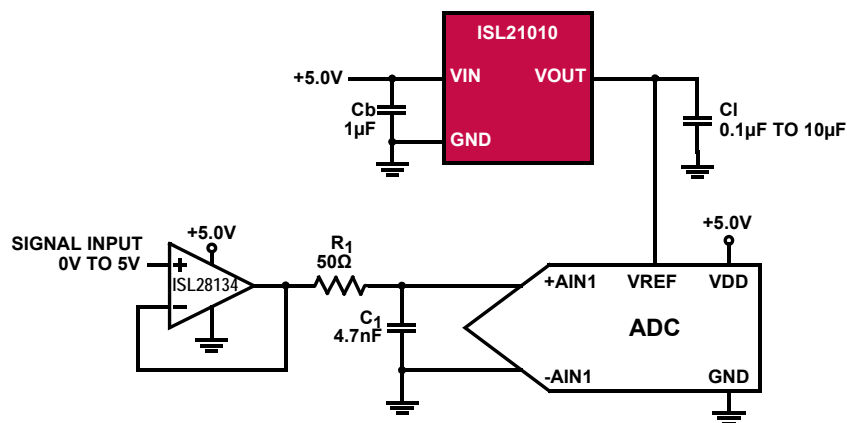


FIGURE 1. TYPICAL APPLICATION DIAGRAM

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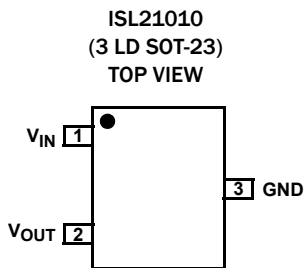
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Typical Application Circuit



FIGURE 2. KELVIN SENSED LOAD

Pin Configuration



Pin Descriptions

PIN NUMBER	PIN NAME	DESCRIPTION
1	V _{IN}	Input Voltage Connection
2	V _{OUT}	Voltage Reference Output
3	GND	Ground Connection

Ordering Information

PART NUMBER (Notes 1, 2, 3, 4)	PART MARKING	TAPE & REEL QUANTITY (UNITS)	V _{OUT} OPTION (V)	INITIAL ACCURACY (%)	TEMP. RANGE (°C)	PACKAGE (RoHS Compliant)	PKG. DWG. #
ISL21010DFH310Z-T	BEBA	3k	1.024	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010DFH310Z-TK	BEBA	1k	1.024	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010DFH310Z-T7A	BEBA	250	1.024	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010DFH312Z-T	BECA	3k	1.25	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010DFH312Z-TK	BECA	1k	1.25	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010DFH312Z-T7A	BECA	250	1.25	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH315Z-TK	BDRA	1k	1.5	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH315Z-T7A	BDRA	250	1.5	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH320Z-TK	BDSA	1k	2.048	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH320Z-T7A	BDSA	250	2.048	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH325Z-TK	BDTA	1k	2.5	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH325Z-T7A	BDTA	250	2.5	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH330Z-TK	BDVA	1k	3.0	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH330Z-T7A	BDVA	250	3.0	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH333Z-TK	BDWA	1k	3.3	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH333Z-T7A	BDWA	250	3.3	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH341Z-TK	BDYA	1k	4.096	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL21010CFH341Z-T7A	BDYA	250	4.096	±0.2	-40 to +125	3 Ld SOT-23	P3.064
ISL2101010EV1Z	ISL21010DFH310Z Evaluation Board						
ISL2101012EV1Z	ISL21010DFH312Z Evaluation Board						
ISL2101015EV1Z	ISL21010CFH315Z Evaluation Board						

NOTES:

1. Refer to [TB347](#) for details about reel specifications.
2. These Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. For Moisture Sensitivity Level (MSL), see the [ISL21010DFH310](#), [ISL21010DFH312](#), [ISL21010CFH315](#), [ISL21010CFH320](#), [ISL21010CFH325](#), [ISL21010CFH330](#), [ISL21010CFH333](#), [ISL21010CFH341](#) product information pages. For more information about MSL, see [TB363](#).
4. The part marking is located on the bottom of the part.

Absolute Maximum Ratings

Max Voltage	
V_{IN} to GND	-0.5V to +6.5V
V_{OUT} (pin) to GND (10s)	-0.5V to V_{IN} +0.5V
Input Voltage Slew Rate (Max)	1V/ μ s
Temperature Range (Industrial)	-40°C to +125°C
ESD Rating	
Human Body Model	5.5kV
Machine Model	300V
Charged Device Model	2kV

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
3 Ld SOT-23 Package (Notes 5, 6)	275	110
Continuous Power Dissipation ($T_A = +125^\circ\text{C}$)	99mW	
Storage Temperature Range	-65°C to +150°C	
Pb-Free Reflow Profile	see TB493	

Recommended Operating Conditions

Temperature	-40°C to +125°C
Supply Voltage	
$V_{OUT} = 1.024\text{V}, 1.25\text{V}, 1.5\text{V}, 2.048\text{V}$	2.2V to 5.5V
$V_{OUT} = 2.5\text{V}$	2.6V to 5.5V
$V_{OUT} = 3.0\text{V}$	3.1V to 5.5V
$V_{OUT} = 3.3\text{V}$	3.4V to 5.5V
$V_{OUT} = 4.096\text{V}$	4.2V to 5.5V

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- θ_{JA} is measured with the component mounted on a high-effective thermal conductivity test board in free air. See [TB379](#) for details.
- For θ_{JC} , the "case temp" location is taken at the package top center.
- Post-reflow drift for the ISL21010 devices may shift up to 4.0mV based on simulated reflow at 260°C peak temperature, three passes. The system design engineer must take this into account when considering the reference voltage after assembly.

Electrical Specifications (ISL21010-10, $V_{OUT} = 1.024\text{V}$) $V_{IN} = 3.0\text{V}$, $T_A = +25^\circ\text{C}$, $I_{OUT} = 0\text{A}$, unless otherwise specified. **Boldface limits apply across the operating temperature range, -40°C to +125°C.**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			1.024		V
V_{OUT} Accuracy at $T_A = +25^\circ\text{C}$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/°C
Input Voltage Range	V_{IN}		2.2		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ\text{C}$		46	80	μA
		$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		60	100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$2.2\text{V} \leq V_{IN} \leq 5.5\text{V}$		5	100	$\mu\text{V}/\text{V}$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0\text{mA} \leq I_{OUT} \leq 25\text{mA}$		15	110	$\mu\text{V}/\text{mA}$
		Sinking: $-1\text{mA} \leq I_{OUT} \leq 0\text{mA}$		17		$\mu\text{V}/\text{mA}$
Short-Circuit Current	I_{SC}	$T_A = +25^\circ\text{C}$, V_{OUT} tied to GND		118		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu\text{F}$		300		μs
Ripple Rejection		$f = 120\text{Hz}$		70		dB
Output Voltage Noise	e_N	$0.1\text{Hz} \leq f \leq 10\text{Hz}$		24		μV_{P-P}
Broadband Voltage Noise	V_N	$10\text{Hz} \leq f \leq 1\text{kHz}$		14		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ\text{C}$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ\text{C}$		110		ppm

Electrical Specifications (ISL21010-12, $V_{OUT} = 1.25V$) $V_{IN} = 3.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified.
Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			1.25		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		2.2		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		46	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$2.2V \leq V_{IN} \leq 5.5V$		1	100	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		35	110	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		50		$\mu V/mA$
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		118		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		68		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		27		μV_{P-P}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		17		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ C$		110		ppm

Electrical Specifications (ISL21010-15, $V_{OUT} = 1.5V$) $V_{IN} = 3.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified.
Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			1.5		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		2.2		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		46	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$2.2V \leq V_{IN} \leq 5.5V$		9	100	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		37	110	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		50		$\mu V/mA$
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		118		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		66		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		35		μV_{P-P}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		20		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ C$		110		ppm

Electrical Specifications (ISL21010-20, $V_{OUT} = 2.048V$) $V_{IN} = 3.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified. **Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			2.048		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		2.2		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		46	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$2.2V \leq V_{IN} \leq 5.5V$		37	130	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		18	110	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		10		$\mu V/mA$
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		118		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		66		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		58		μV_{P-P}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		26		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ C$		50		ppm

Electrical Specifications (ISL21010-25, $V_{OUT} = 2.5V$) $V_{IN} = 3.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified. **Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			2.5		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		2.6		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		46	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$2.6V \leq V_{IN} \leq 5.5V$		62	245	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		29	110	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		50		$\mu V/mA$
Dropout Voltage (Note 10)	V_{INDO}	$I_{OUT} = 10mA$		60	150	mV
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		118		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		62		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		67		μV_{P-P}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		37		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ C$		110		ppm

Electrical Specifications (ISL21010-30, $V_{OUT} = 3.0V$) $V_{IN} = 5.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified.
Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			3.0		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		3.1		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		48	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$3.1V \leq V_{IN} \leq 5.5V$		73	230	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		48	110	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		10		$\mu V/mA$
Dropout Voltage (Note 10)	V_{INDO}	$I_{OUT} = 10mA$		60	150	mV
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		126		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		62		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		86		μV_{p-p}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		36		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ C$		50		ppm

Electrical Specifications (ISL21010-33, $V_{OUT} = 3.3V$) $V_{IN} = 5.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified.
Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			3.3		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		3.4		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		48	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$3.4V \leq V_{IN} \leq 5.5V$		80	320	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		45	110	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		10		$\mu V/mA$
Dropout Voltage (Note 10)	V_{INDO}	$I_{OUT} = 10mA$		60	150	mV
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		126		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		61		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		95		μV_{p-p}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		40		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT}/\Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT}/\Delta t$	1000 hours, $T_A = +25^\circ C$		50		ppm

Electrical Specifications (ISL21010-41, $V_{OUT} = 4.096V$) $V_{IN} = 5.0V$, $T_A = +25^\circ C$, $I_{OUT} = 0A$, unless otherwise specified. **Boldface limits apply across the operating temperature range, $-40^\circ C$ to $+125^\circ C$.**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 8)	TYP	MAX (Note 8)	UNIT
Output Voltage	V_{OUT}			4.096		V
V_{OUT} Accuracy at $T_A = +25^\circ C$ (Note 7)	V_{OA}		-0.2		+0.2	%
Output Voltage Temperature Coefficient (Note 9)	TC V_{OUT}			15	50	ppm/ $^\circ C$
Input Voltage Range	V_{IN}		4.2		5.5	V
Supply Current	I_{IN}	$T_A = +25^\circ C$		48	80	μA
		$T_A = -40^\circ C$ to $+125^\circ C$			100	μA
Line Regulation	$\Delta V_{OUT} / \Delta V_{IN}$	$4.2 V \leq V_{IN} \leq 5.5V$		106	550	$\mu V/V$
Load Regulation	$\Delta V_{OUT} / \Delta I_{OUT}$	Sourcing: $0mA \leq I_{OUT} \leq 25mA$		50	140	$\mu V/mA$
		Sinking: $-1mA \leq I_{OUT} \leq 0mA$		50		$\mu V/mA$
Dropout Voltage (Note 10)	V_{INDO}	$I_{OUT} = 10mA$		60	150	mV
Short-Circuit Current	I_{SC}	$T_A = +25^\circ C$, V_{OUT} tied to GND		126		mA
Turn-On Settling Time	t_R	$V_{OUT} = \pm 0.1\%$, $C_{OUT} = 1\mu F$		300		μs
Ripple Rejection		$f = 120Hz$		58		dB
Output Voltage Noise	e_N	$0.1Hz \leq f \leq 10Hz$		112		μV_{P-P}
Broadband Voltage Noise	V_N	$10Hz \leq f \leq 1kHz$		56		μV_{RMS}
Thermal Hysteresis (Note 11)	$\Delta V_{OUT} / \Delta T_A$	$\Delta T_A = +165^\circ C$		100		ppm
Long Term Stability	$\Delta V_{OUT} / \Delta t$	1000 hours, $T_A = +25^\circ C$		110		ppm

NOTES:

8. Compliance to datasheet limits is assured by one or more methods: production test, characterization, and/or design.
9. Over the specified temperature range. Temperature coefficient is measured by the box method whereby the change in V_{OUT} is divided by the temperature range; in this case, $-40^\circ C$ to $+125^\circ C = +165^\circ C$.
10. Dropout Voltage is the minimum $V_{IN} - V_{OUT}$ differential voltage measured at the point where V_{OUT} drops 1mV from $V_{IN} =$ nominal at $T_A = +25^\circ C$.
11. Thermal Hysteresis is the change of V_{OUT} measured at $T_A = +25^\circ C$ after temperature cycling over a specified range, ΔT_A . V_{OUT} is read initially at $T_A = +25^\circ C$ for the device under test. The device is temperature cycled and a second V_{OUT} measurement is taken at $+25^\circ C$. The difference between the initial V_{OUT} reading and the second V_{OUT} reading is then expressed in ppm. For $\Delta T_A = +165^\circ C$, the device under test is cycled from $+25^\circ C$ to $-40^\circ C$ to $+125^\circ C$ to $+25^\circ C$.

Typical Performance Characteristics Curves ($V_{OUT} = 1.024V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified.

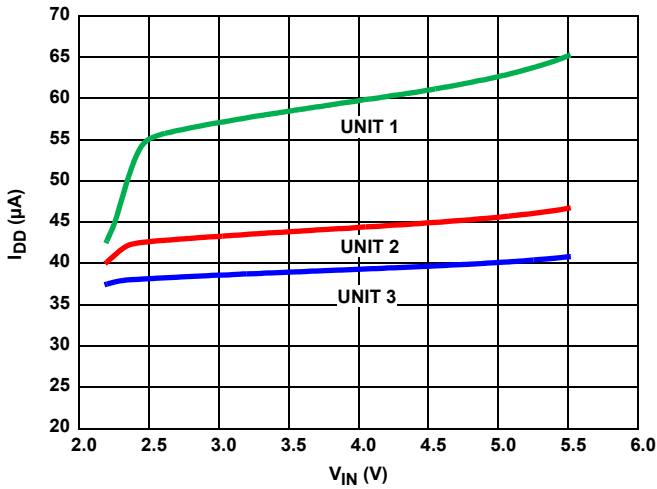


FIGURE 3. I_{IN} vs V_{IN} , THREE UNITS

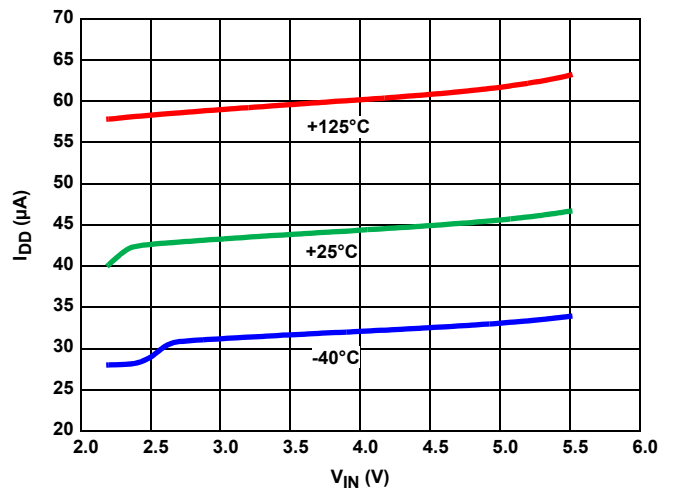


FIGURE 4. I_{IN} vs V_{IN} , OVER-TEMPERATURE

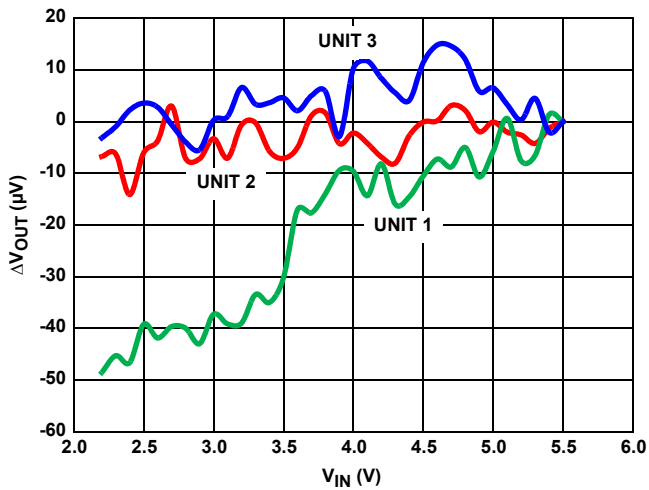


FIGURE 5. LINE REGULATION, THREE UNITS

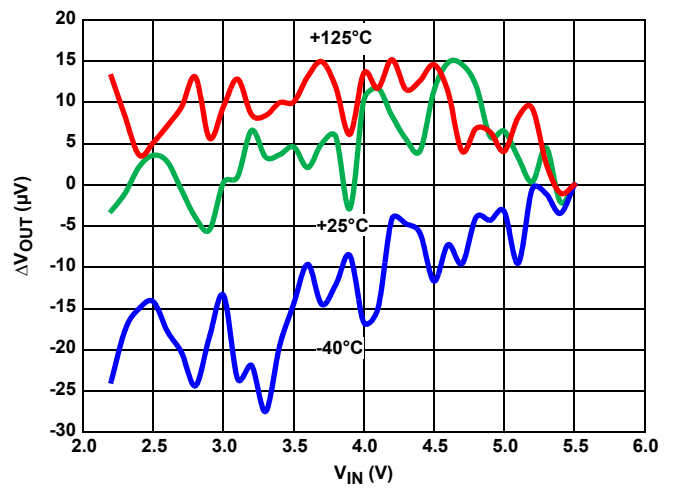


FIGURE 6. LINE REGULATION OVER-TEMPERATURE

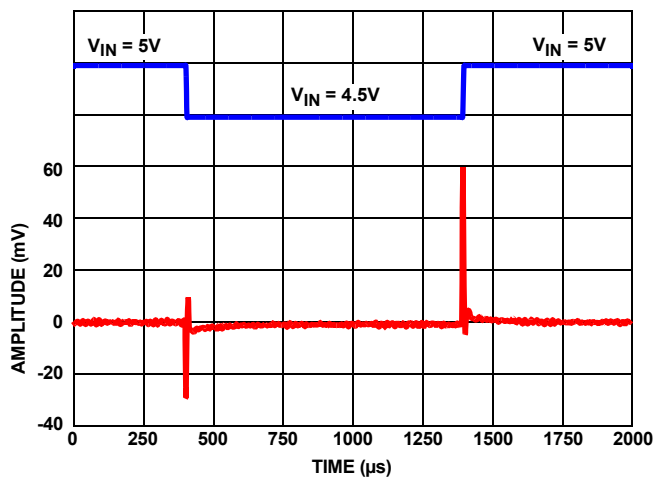


FIGURE 7. LINE TRANSIENT RESPONSE WITH $0.22\mu F$ LOAD

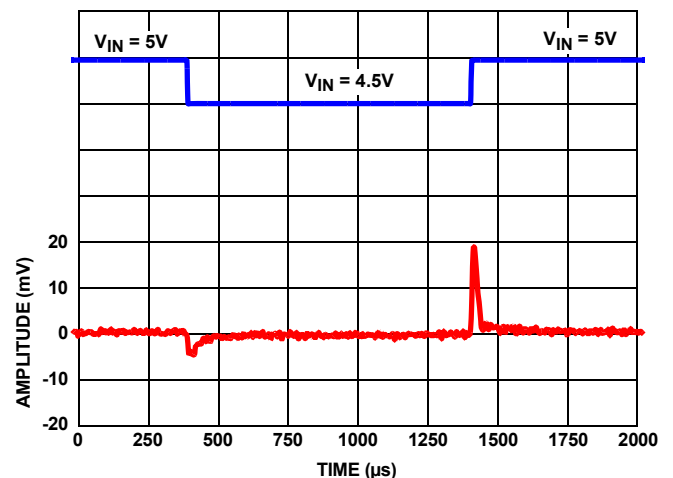


FIGURE 8. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 1.024V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)

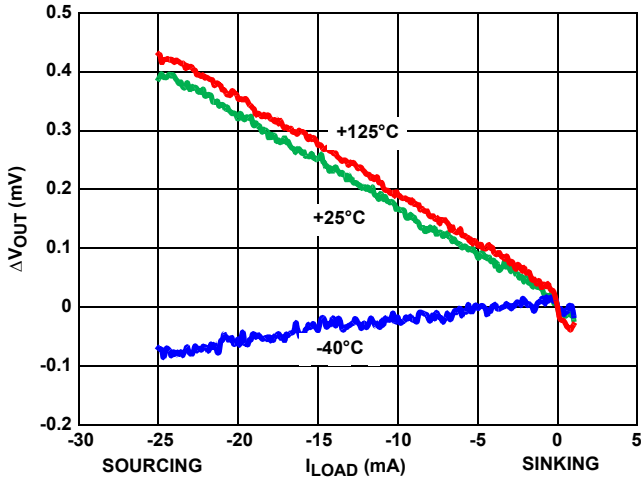


FIGURE 9. LOAD REGULATION OVER-TEMPERATURE

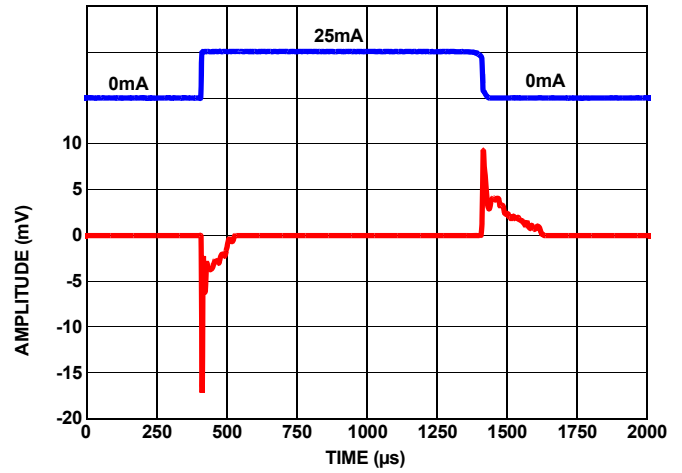


FIGURE 10. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF



FIGURE 11. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF

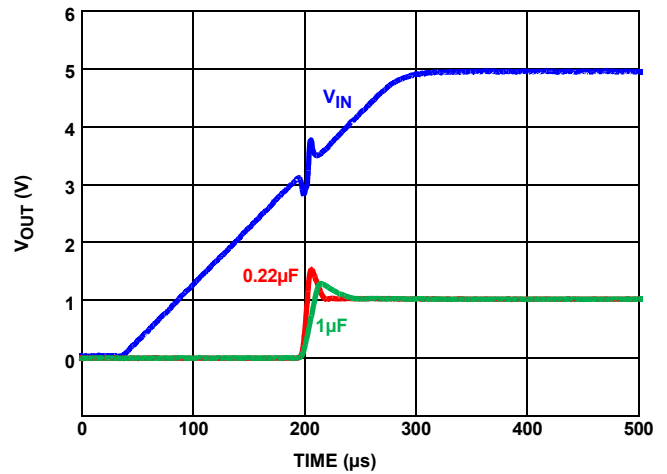


FIGURE 12. TURN-ON TIME

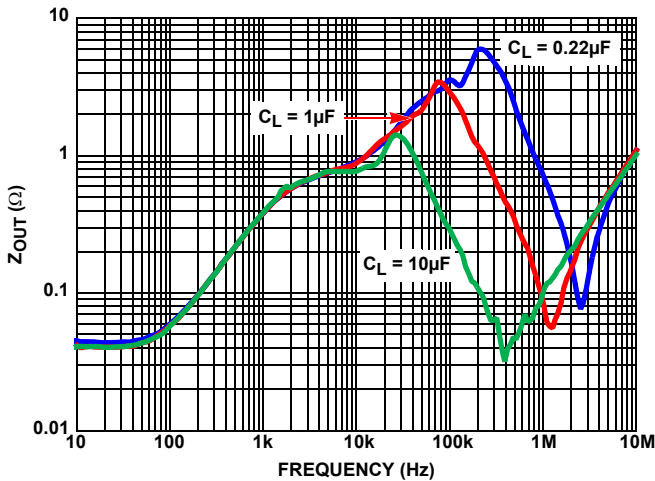


FIGURE 13. Z_{OUT} vs FREQUENCY

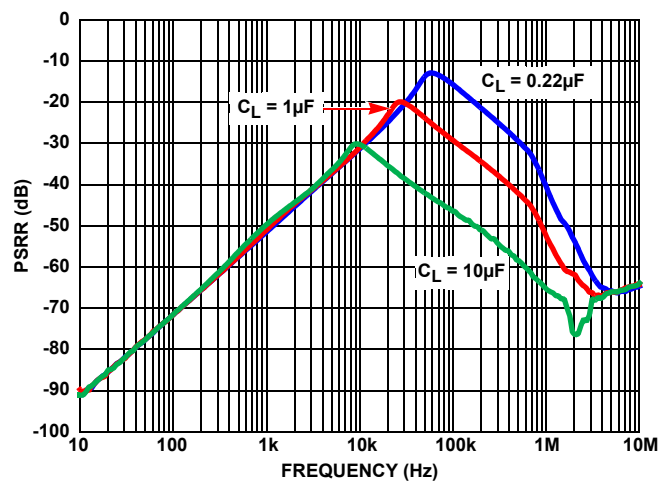


FIGURE 14. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 1.024V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)



FIGURE 15. DROPOUT (10mA SOURCED LOAD)

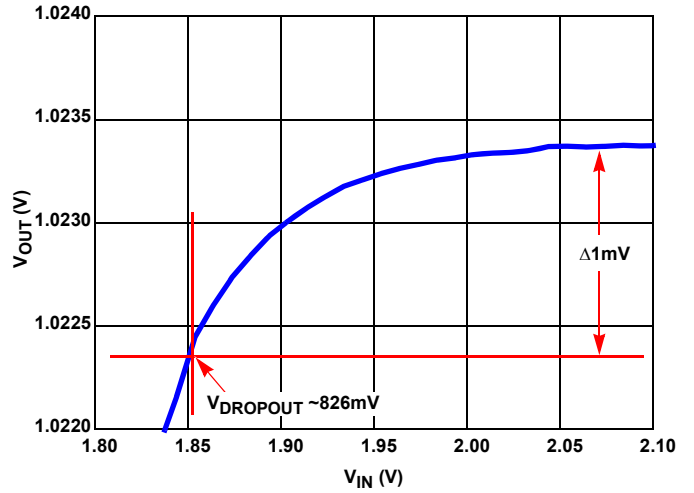


FIGURE 16. DROPOUT ZOOMED (10mA SOURCED LOAD)



FIGURE 17. V_{OUT} vs TEMPERATURE

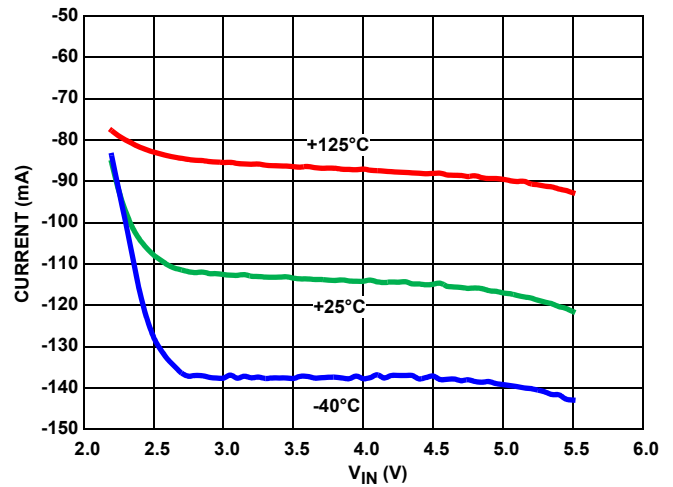


FIGURE 18. SHORT CIRCUIT TO GND



FIGURE 19. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 1.25V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified.



FIGURE 20. I_{IN} vs V_{IN} , THREE UNITS

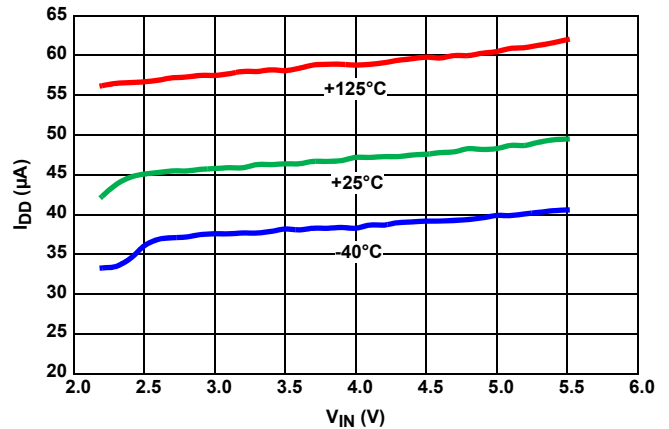


FIGURE 21. I_{IN} vs V_{IN} , OVER-TEMPERATURE

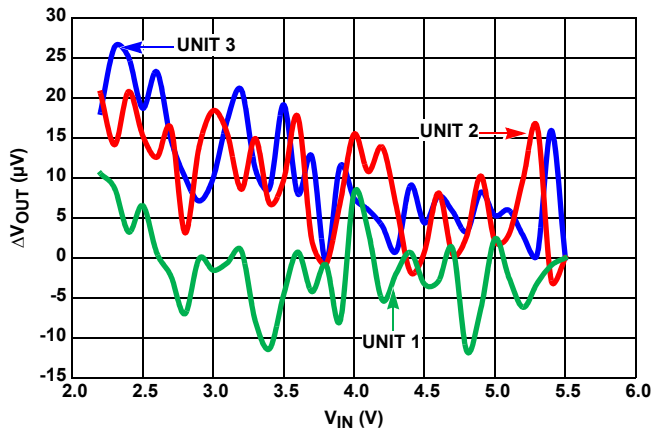


FIGURE 22. LINE REGULATION, THREE UNITS

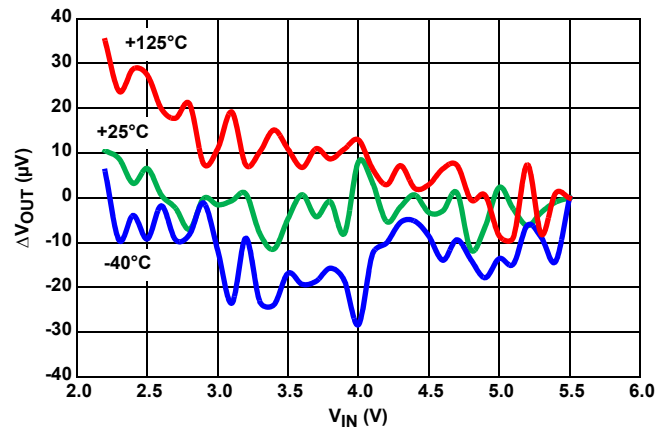


FIGURE 23. LINE REGULATION OVER-TEMPERATURE



FIGURE 24. LINE TRANSIENT RESPONSE WITH $0.1\mu F$ LOAD

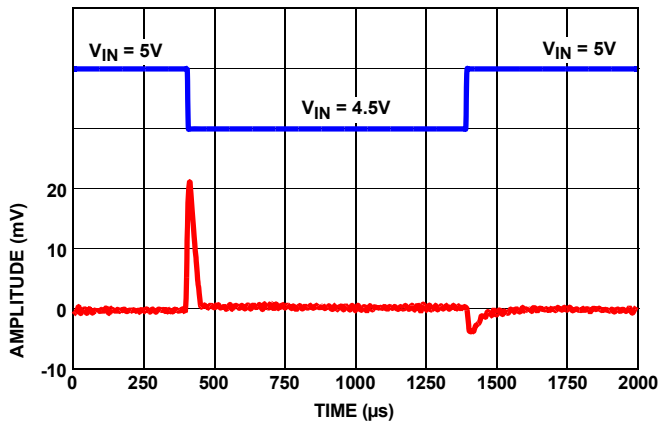


FIGURE 25. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 1.25V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)

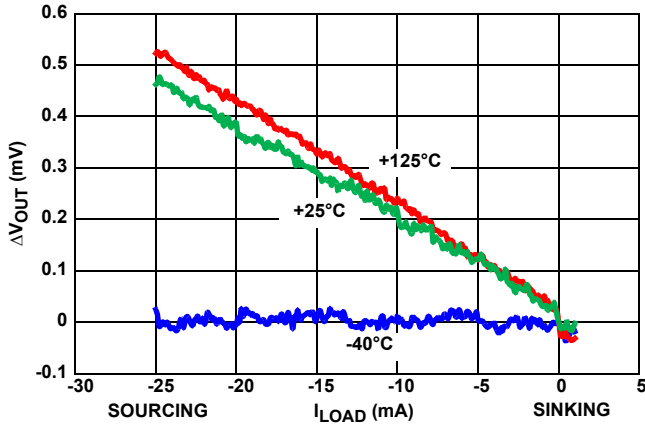


FIGURE 26. LOAD REGULATION OVER-TEMPERATURE



FIGURE 27. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF



FIGURE 28. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF



FIGURE 29. TURN-ON TIME

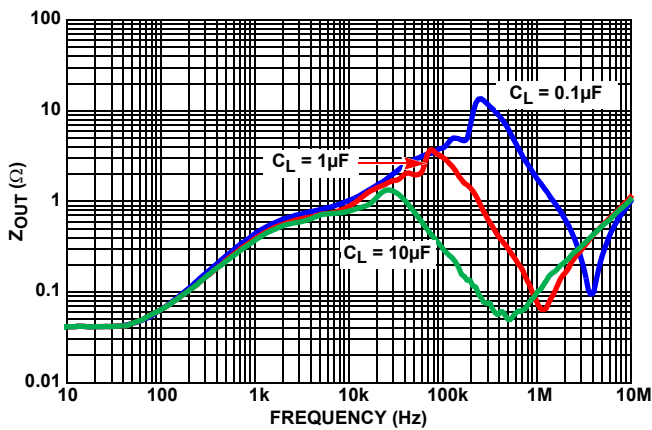


FIGURE 30. Z_{OUT} vs FREQUENCY

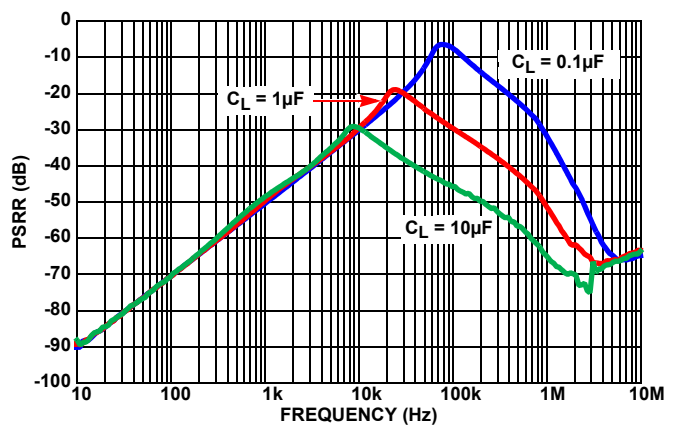


FIGURE 31. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 1.25V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)



FIGURE 32. DROPOUT (10mA SOURCED LOAD)

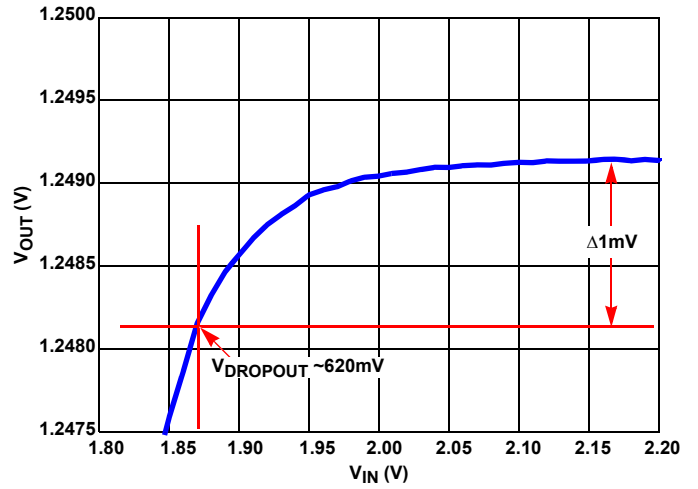


FIGURE 33. DROPOUT ZOOMED (10mA SOURCED LOAD)



FIGURE 34. V_{OUT} vs TEMPERATURE

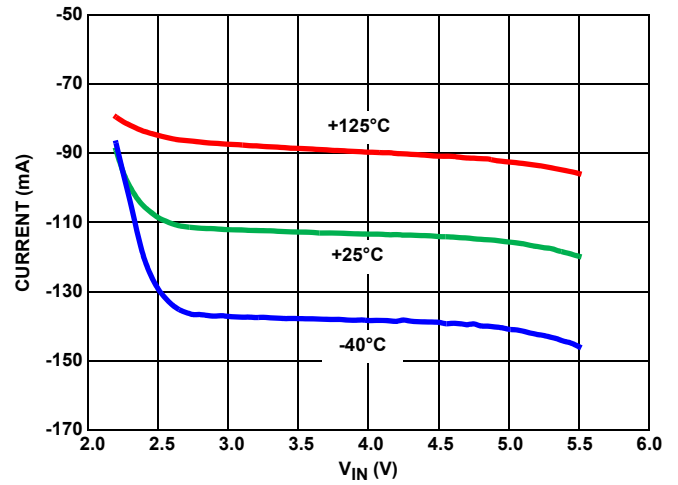


FIGURE 35. SHORT-CIRCUIT TO GND



FIGURE 36. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 1.5V$) $V_{IN} = 3.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified.



FIGURE 37. I_{IN} vs V_{IN} , THREE UNITS

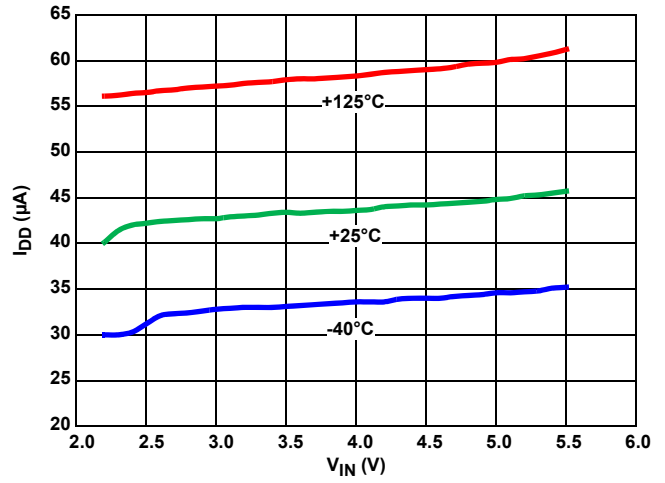


FIGURE 38. I_{IN} vs V_{IN} , OVER-TEMPERATURE

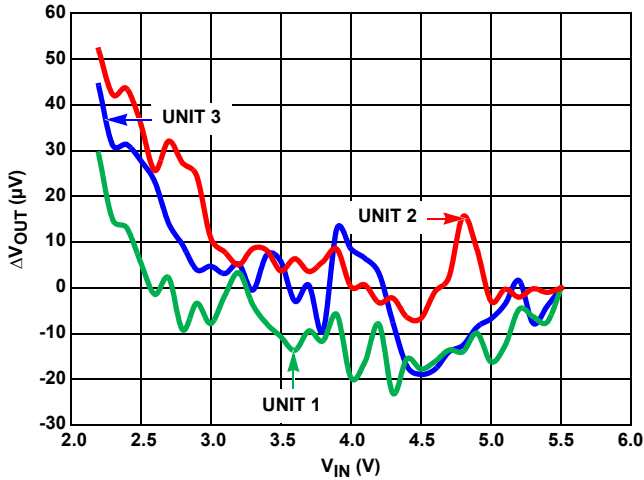


FIGURE 39. LINE REGULATION, THREE UNITS

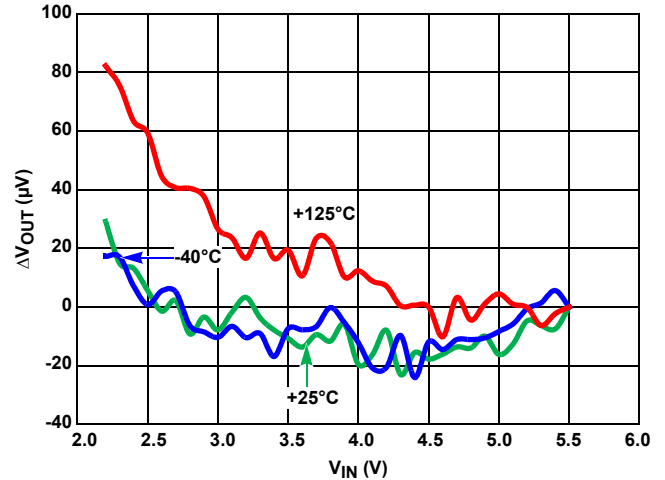


FIGURE 40. LINE REGULATION OVER-TEMPERATURE



FIGURE 41. LINE TRANSIENT RESPONSE WITH $0.1\mu F$ LOAD



FIGURE 42. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 1.5V$) $V_{IN} = 3.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

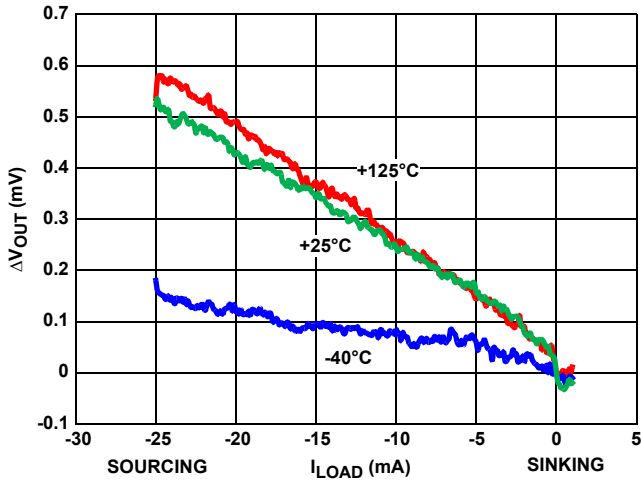


FIGURE 43. LOAD REGULATION OVER-TEMPERATURE



FIGURE 44. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF



FIGURE 45. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF

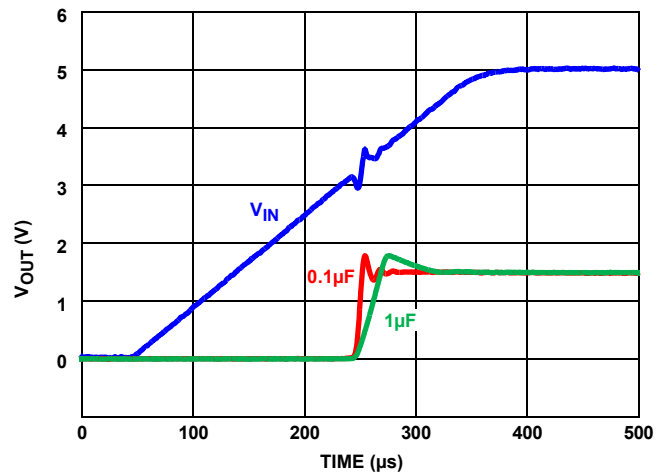


FIGURE 46. TURN-ON TIME

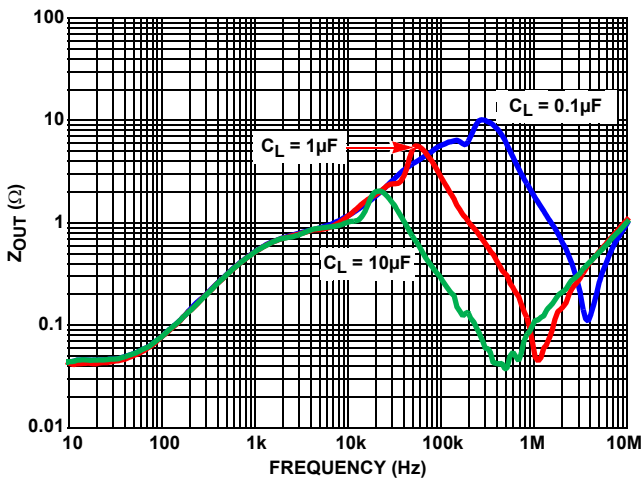


FIGURE 47. Z_{OUT} vs FREQUENCY



FIGURE 48. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 1.5V$) $V_{IN} = 3.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

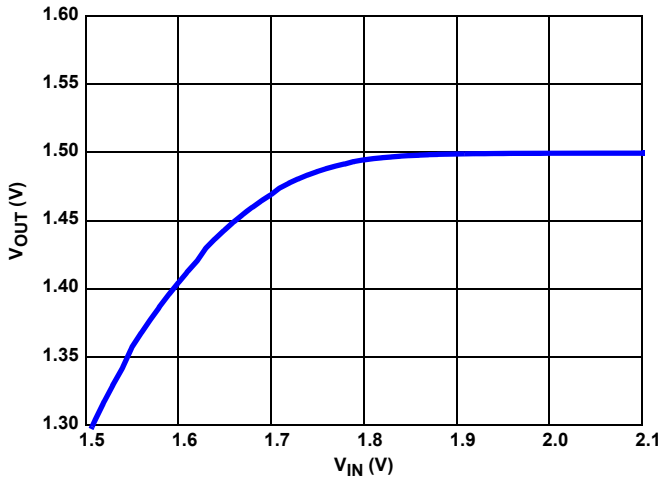


FIGURE 49. DROPOUT (10mA SOURCED LOAD)

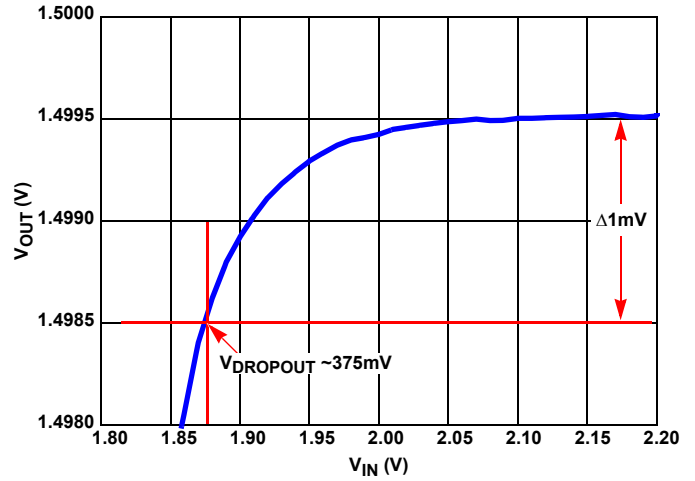


FIGURE 50. DROPOUT ZOOMED (10mA SOURCED LOAD)

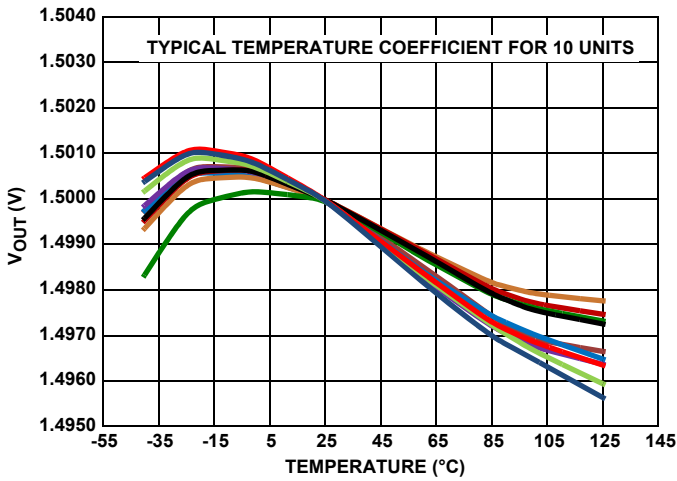


FIGURE 51. V_{OUT} vs TEMPERATURE

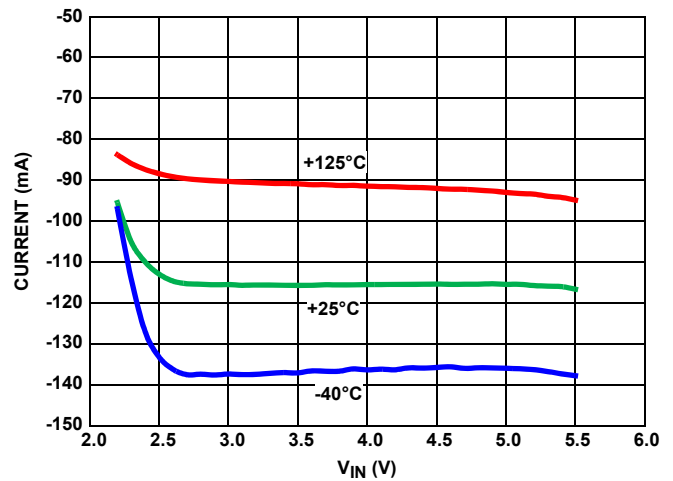


FIGURE 52. SHORT-CIRCUIT TO GND



FIGURE 53. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 2.048V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified.

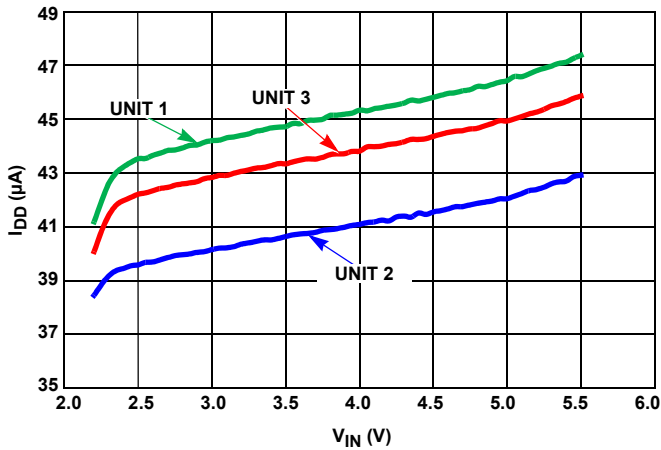


FIGURE 54. I_{IN} vs V_{IN} , THREE UNITS



FIGURE 55. I_{IN} vs V_{IN} , OVER-TEMPERATURE

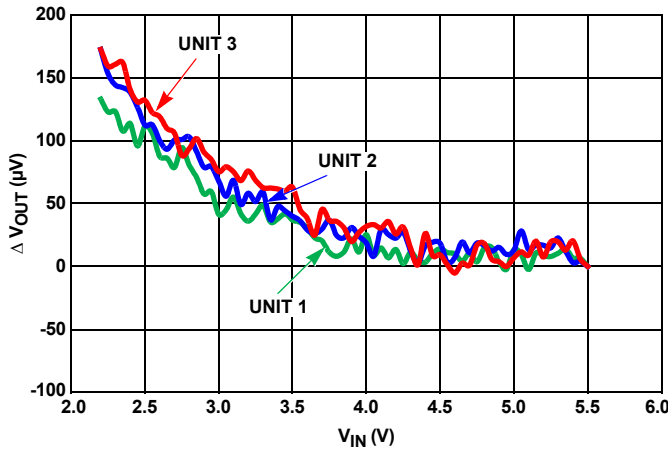


FIGURE 56. LINE REGULATION, THREE UNITS

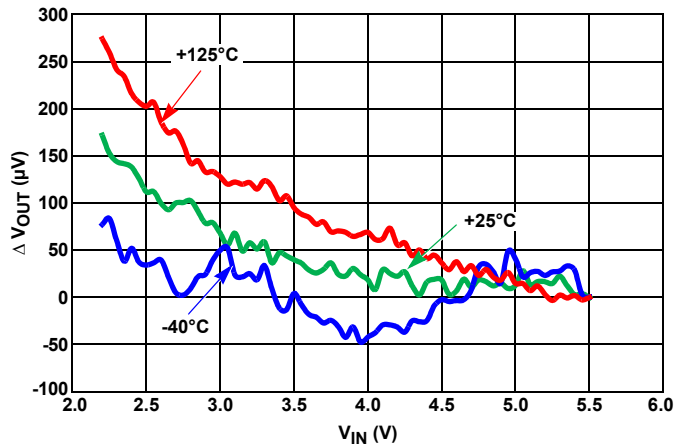


FIGURE 57. LINE REGULATION OVER-TEMPERATURE

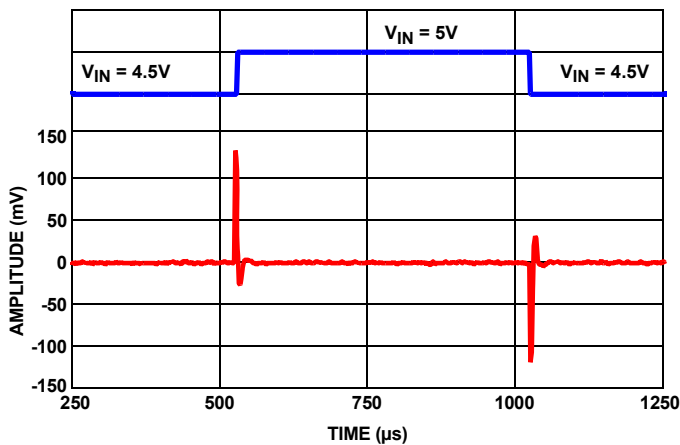


FIGURE 58. LINE TRANSIENT RESPONSE WITH $0.1\mu F$ LOAD

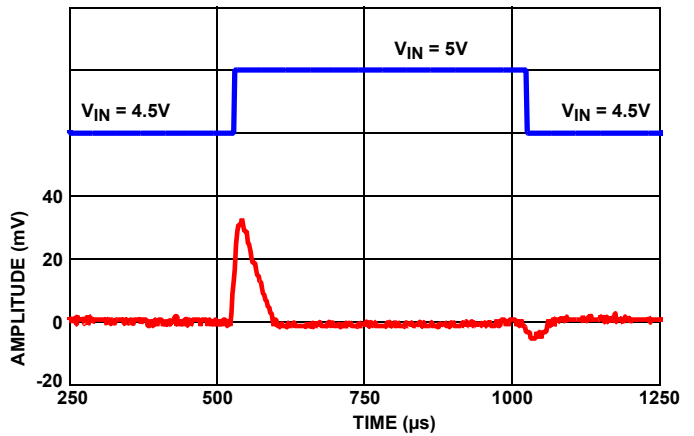


FIGURE 59. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 2.048V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)

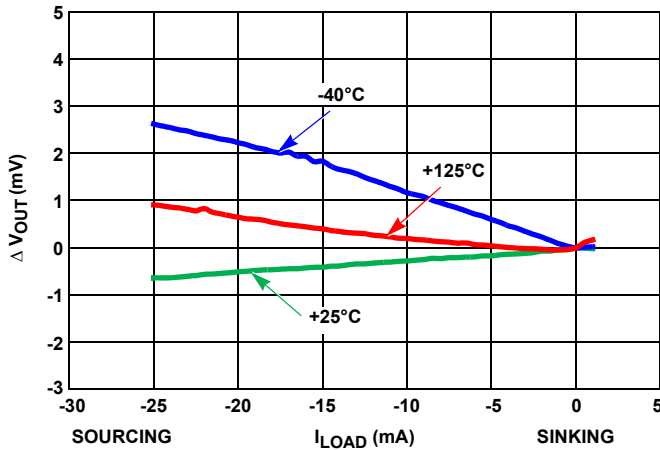


FIGURE 60. LOAD REGULATION OVER-TEMPERATURE



FIGURE 61. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1μF

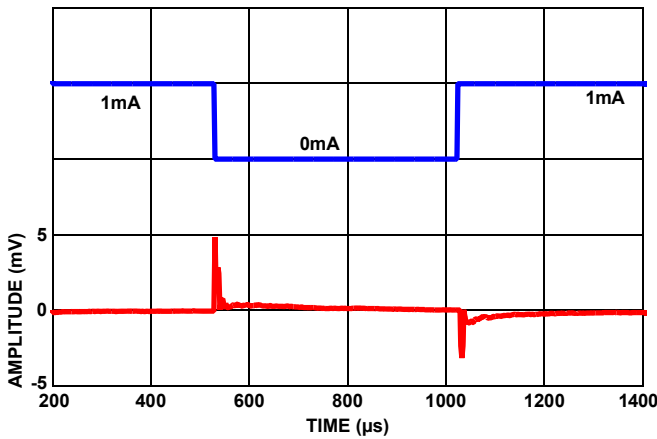


FIGURE 62. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1μF

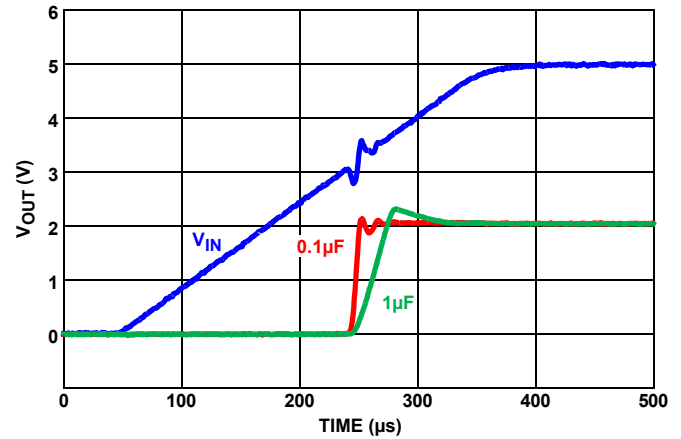


FIGURE 63. TURN-ON TIME



FIGURE 64. Z_{OUT} vs FREQUENCY



FIGURE 65. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 2.048V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)



FIGURE 66. DROPOUT (10mA SOURCED LOAD)

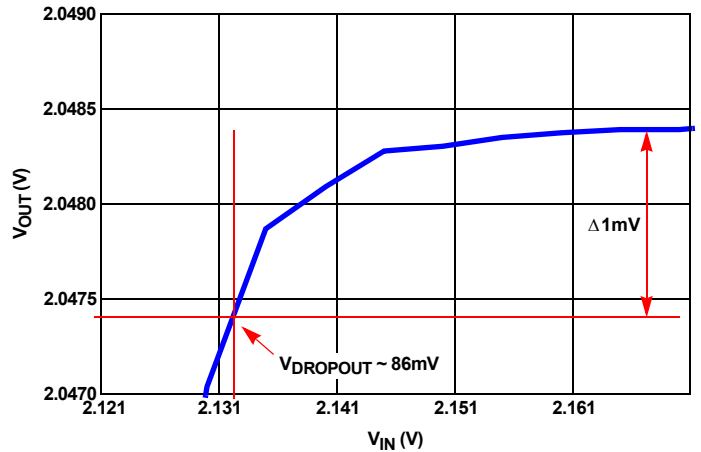


FIGURE 67. DROPOUT ZOOMED (10mA SOURCED LOAD)

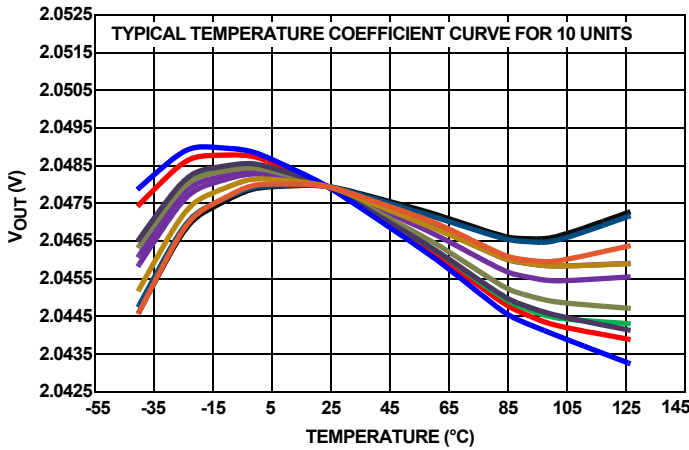


FIGURE 68. V_{OUT} vs TEMPERATURE

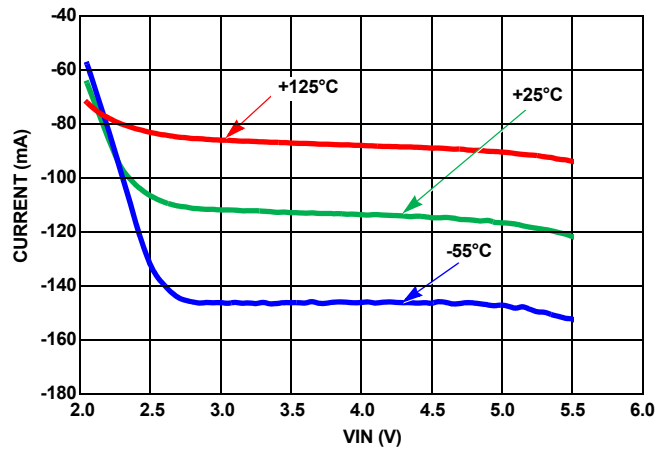


FIGURE 69. SHORT CIRCUIT TO GND



FIGURE 70. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 2.5V$) $V_{IN} = 3.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified.



FIGURE 71. I_{IN} vs V_{IN} , THREE UNITS



FIGURE 72. I_{IN} vs V_{IN} , OVER-TEMPERATURE

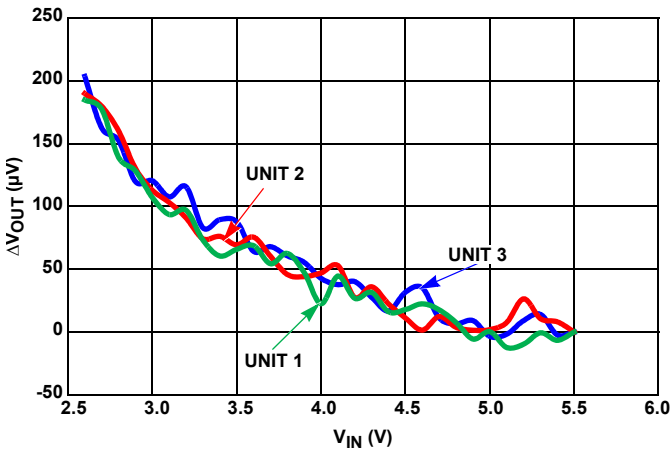


FIGURE 73. LINE REGULATION, THREE UNITS

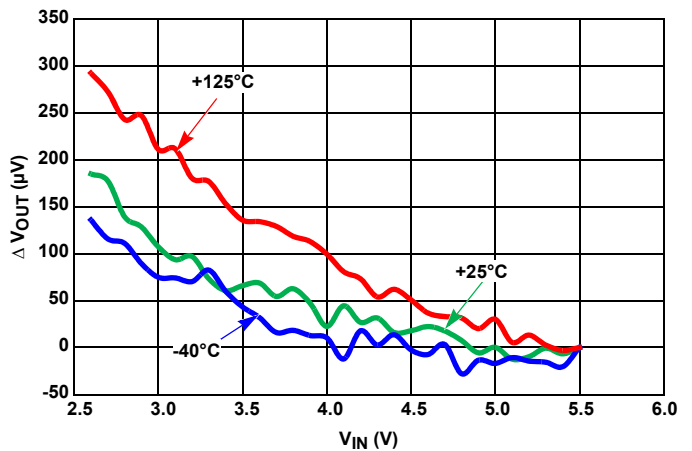


FIGURE 74. LINE REGULATION OVER-TEMPERATURE



FIGURE 75. LINE TRANSIENT RESPONSE WITH $0.1\mu F$ LOAD



FIGURE 76. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 2.5V$) $V_{IN} = 3.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

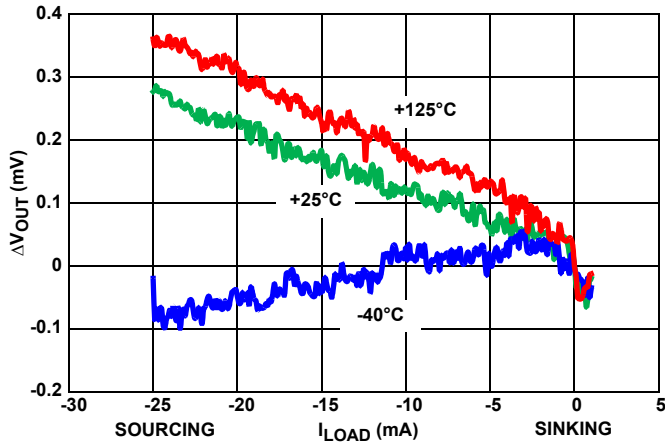


FIGURE 77. LOAD REGULATION OVER-TEMPERATURE



FIGURE 78. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF



FIGURE 79. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF



FIGURE 80. TURN-ON TIME

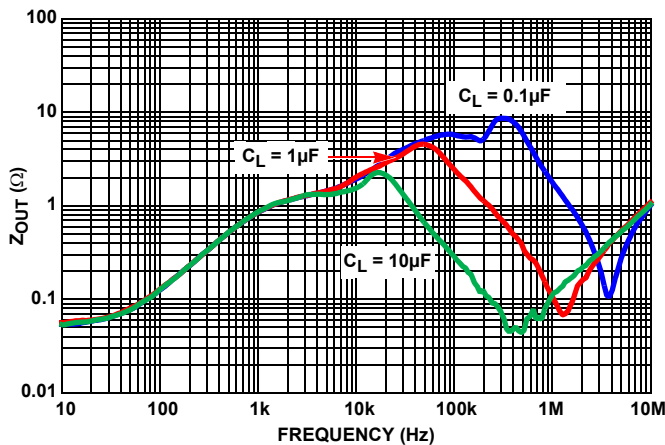


FIGURE 81. Z_{OUT} vs FREQUENCY

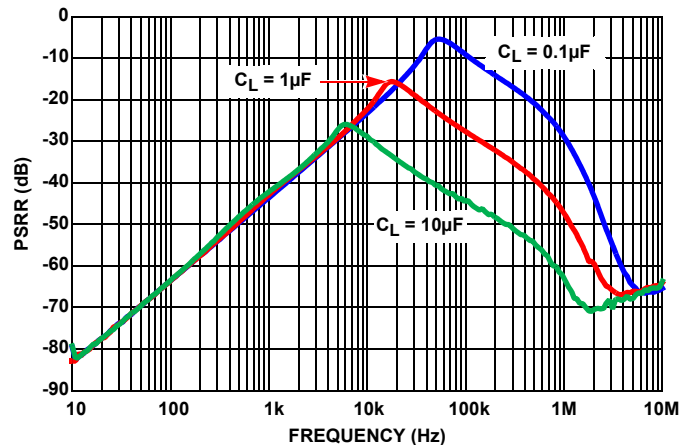


FIGURE 82. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 2.5V$) $V_{IN} = 3.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

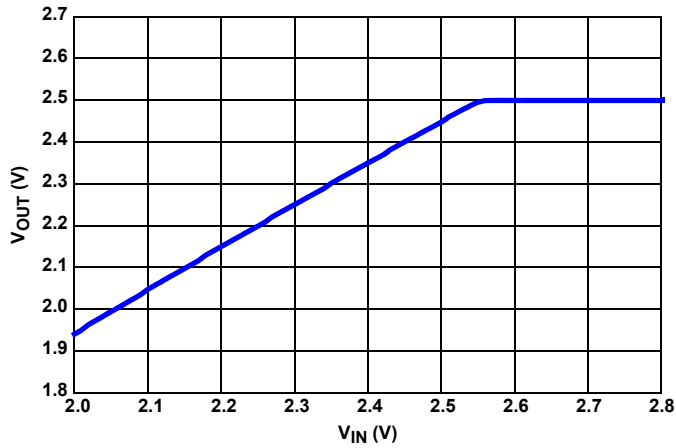


FIGURE 83. DROPOUT (10mA SOURCED LOAD)

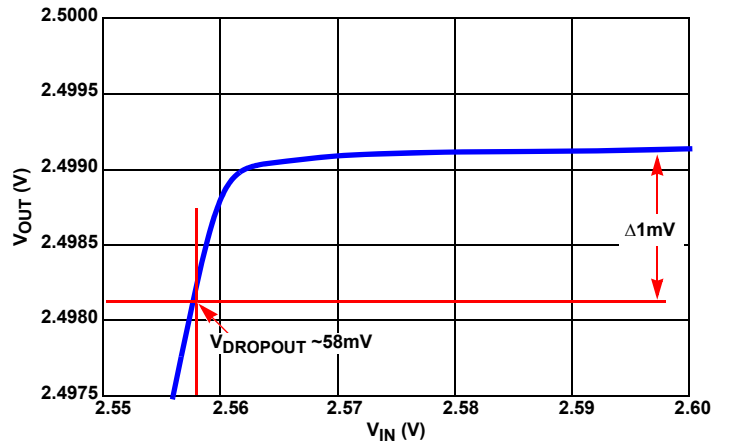


FIGURE 84. DROPOUT ZOOMED (10mA SOURCED LOAD)



FIGURE 85. V_{OUT} vs TEMPERATURE



FIGURE 86. SHORT-CIRCUIT TO GND



FIGURE 87. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 3.0V$) $V_{IN} = 5.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified.



FIGURE 88. I_{IN} vs V_{IN} , THREE UNITS



FIGURE 89. I_{IN} vs V_{IN} , OVER-TEMPERATURE

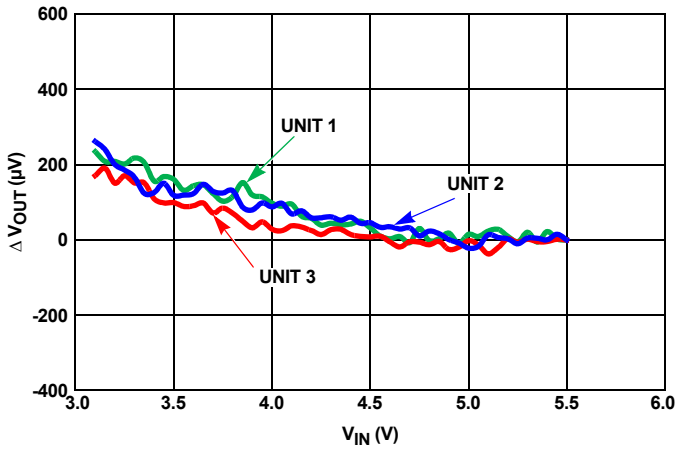


FIGURE 90. LINE REGULATION, THREE UNITS

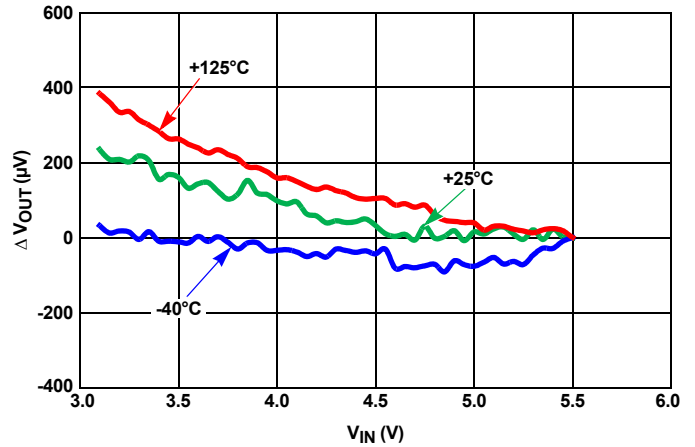


FIGURE 91. LINE REGULATION OVER-TEMPERATURE

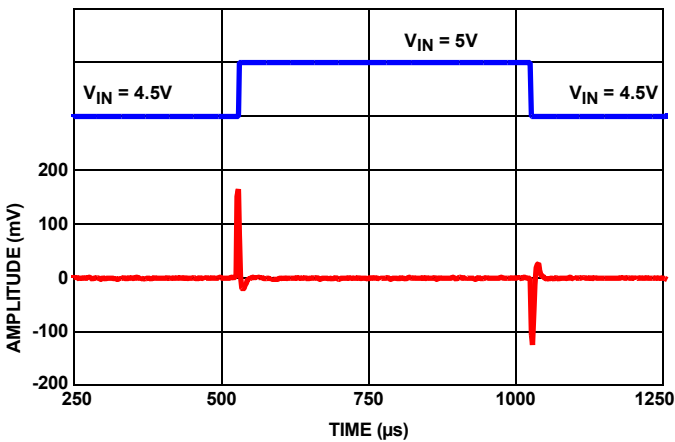


FIGURE 92. LINE TRANSIENT WITH $0.1\mu F$ LOAD



FIGURE 93. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 3.0V$) $V_{IN} = 5.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

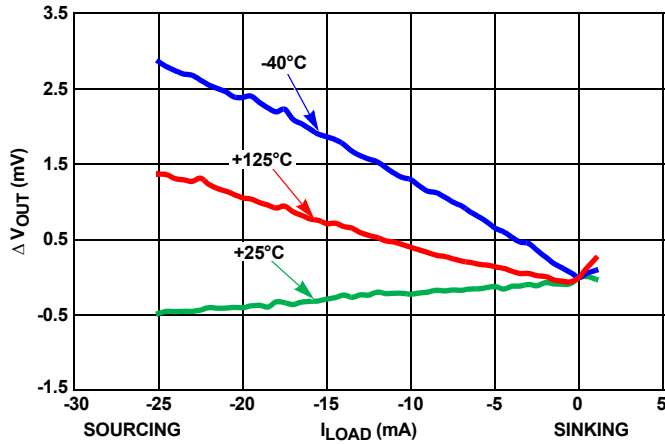


FIGURE 94. LOAD REGULATION OVER-TEMPERATURE

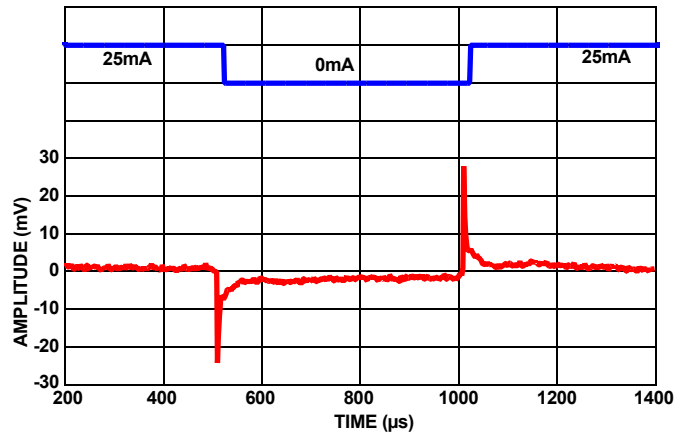


FIGURE 95. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF



FIGURE 96. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF



FIGURE 97. TURN-ON TIME



FIGURE 98. Z_{OUT} vs FREQUENCY



FIGURE 99. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 3.0V$) $V_{IN} = 5.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

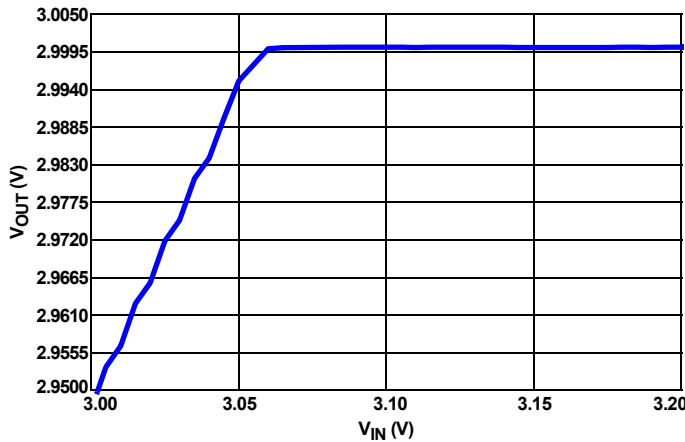


FIGURE 100. DROPOUT (10mA SOURCED LOAD)

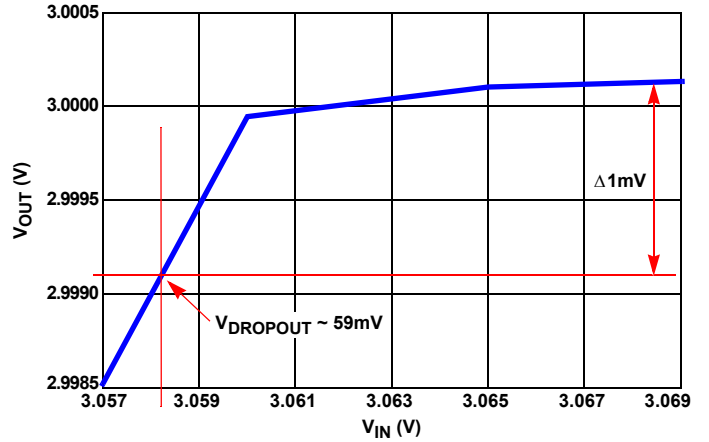


FIGURE 101. DROPOUT ZOOMED (10mA SOURCED LOAD)



FIGURE 102. V_{OUT} vs TEMPERATURE

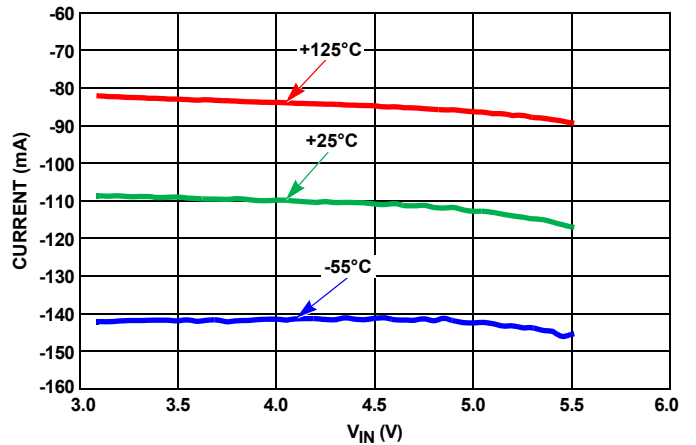


FIGURE 103. SHORT-CIRCUIT TO GND



FIGURE 104. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 3.3V$) $V_{IN} = 5.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified.



FIGURE 105. I_{IN} vs V_{IN} , THREE UNITS



FIGURE 106. I_{IN} vs V_{IN} , OVER-TEMPERATURE

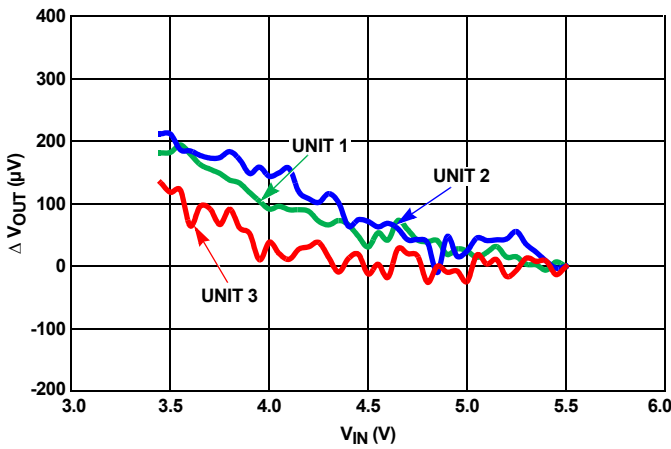


FIGURE 107. LINE REGULATION, THREE UNITS

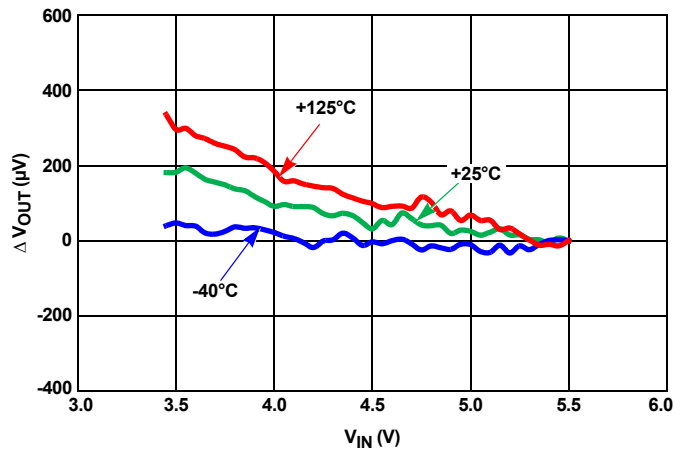


FIGURE 108. LINE REGULATION OVER-TEMPERATURE



FIGURE 109. LINE TRANSIENT WITH $0.1\mu F$ LOAD



FIGURE 110. LINE TRANSIENT RESPONSE WITH $10\mu F$ LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 3.3V$) $V_{IN} = 5.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)

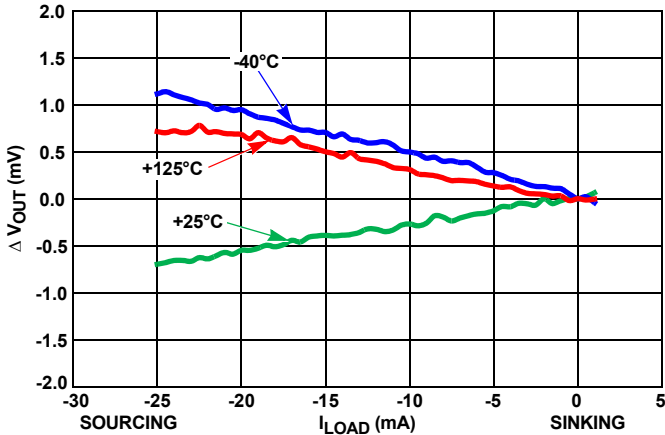


FIGURE 111. LOAD REGULATION OVER-TEMPERATURE



FIGURE 112. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF

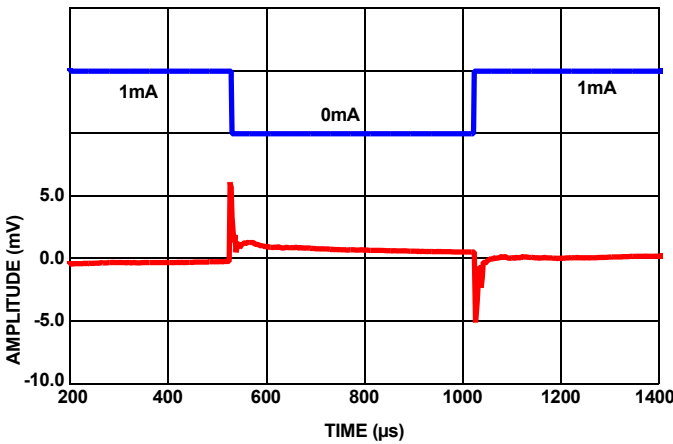


FIGURE 113. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF



FIGURE 114. TURN-ON TIME

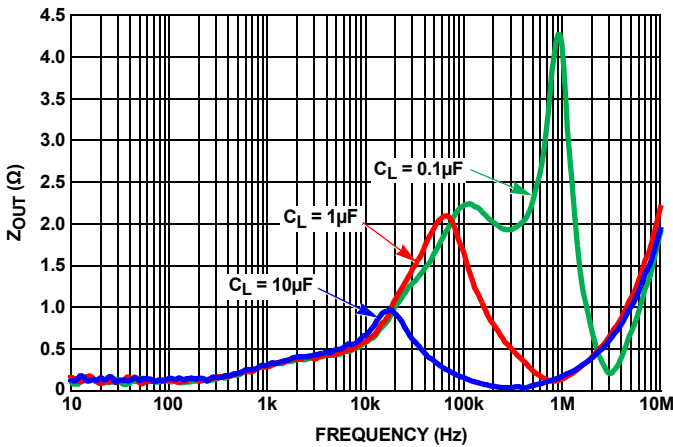


FIGURE 115. Z_{OUT} vs FREQUENCY

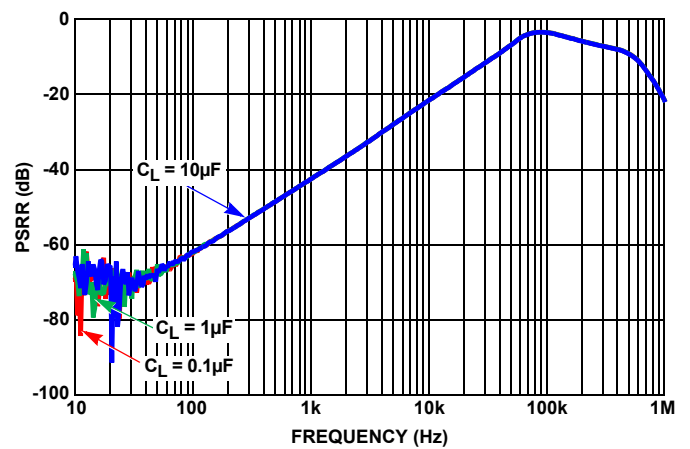


FIGURE 116. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 3.3V$) $V_{IN} = 5.0V, I_{OUT} = 0mA,$
 $T_A = +25^\circ C$ unless otherwise specified. (Continued)



FIGURE 117. DROPOUT (10mA SOURCED LOAD)

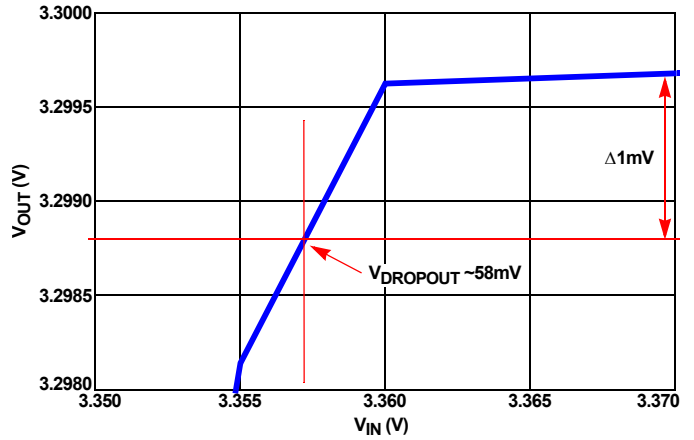


FIGURE 118. DROPOUT ZOOMED (10mA SOURCED LOAD)



FIGURE 119. V_{OUT} vs TEMPERATURE



FIGURE 120. SHORT-CIRCUIT TO GND



FIGURE 121. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Typical Performance Characteristics Curves ($V_{OUT} = 4.096V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified.



FIGURE 122. I_{IN} vs V_{IN} , THREE UNITS



FIGURE 123. I_{IN} vs V_{IN} , OVER-TEMPERATURE

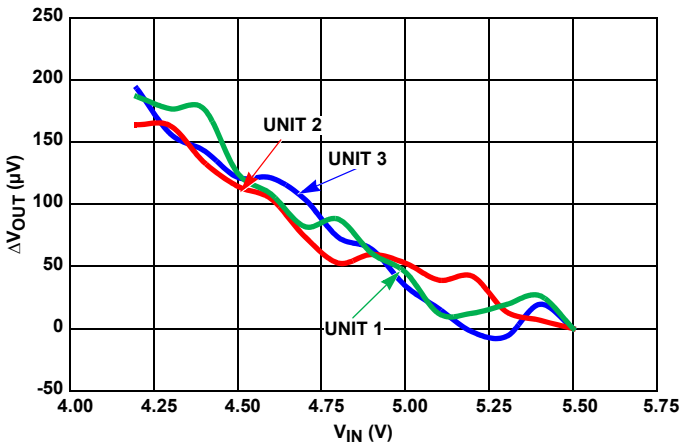


FIGURE 124. LINE REGULATION, THREE UNITS

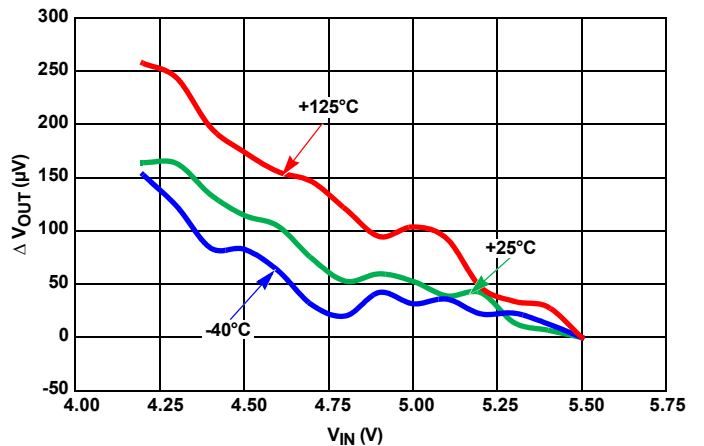


FIGURE 125. LINE REGULATION OVER-TEMPERATURE



FIGURE 126. LINE TRANSIENT RESPONSE WITH 0.1µF LOAD



FIGURE 127. LINE TRANSIENT RESPONSE WITH 10µF LOAD

Typical Performance Characteristics Curves ($V_{OUT} = 4.096V$) $V_{IN} = 3.0V$, $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)

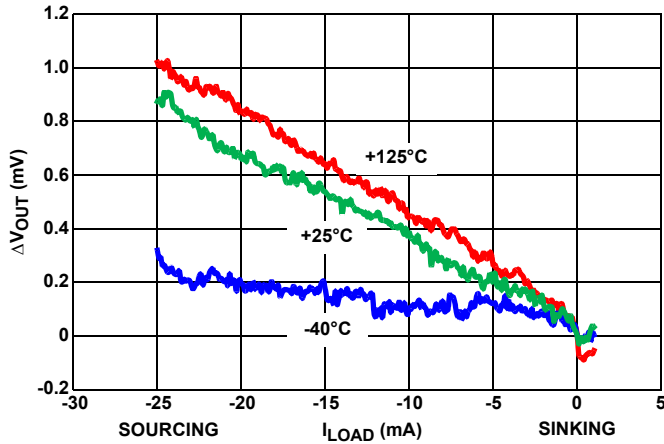


FIGURE 128. LOAD REGULATION OVER-TEMPERATURE



FIGURE 129. LOAD TRANSIENT RESPONSE AT 25mA LOAD AT 1µF

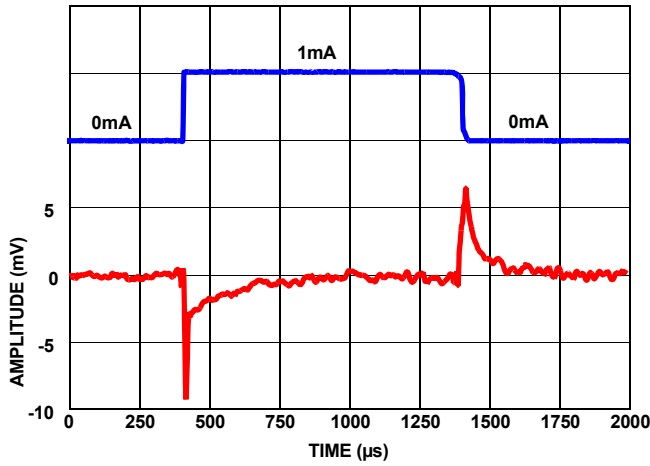


FIGURE 130. LOAD TRANSIENT RESPONSE AT 1mA LOAD AT 1µF

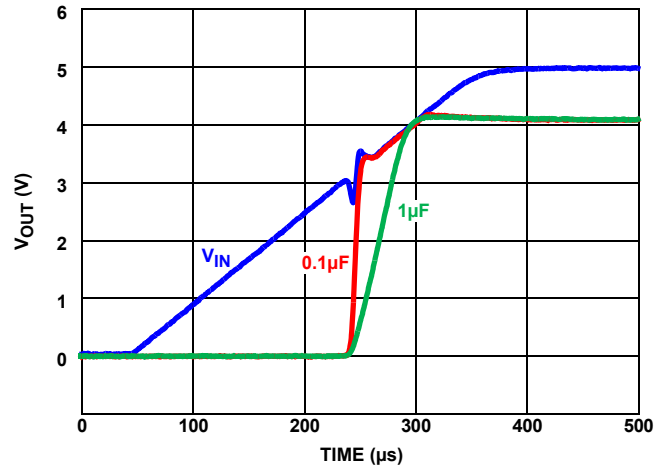


FIGURE 131. TURN-ON TIME

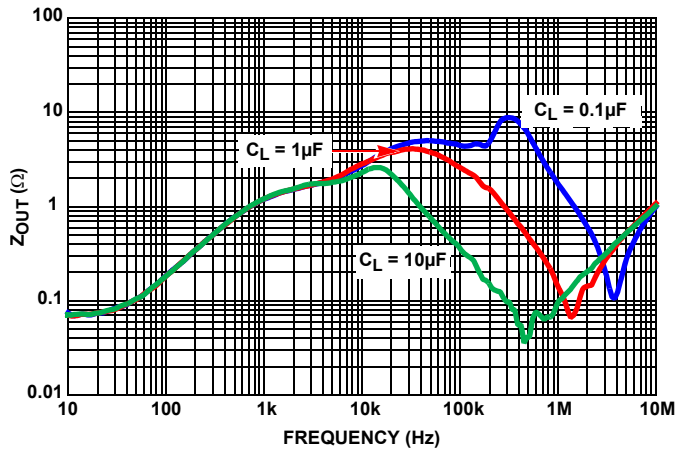


FIGURE 132. Z_{OUT} vs FREQUENCY

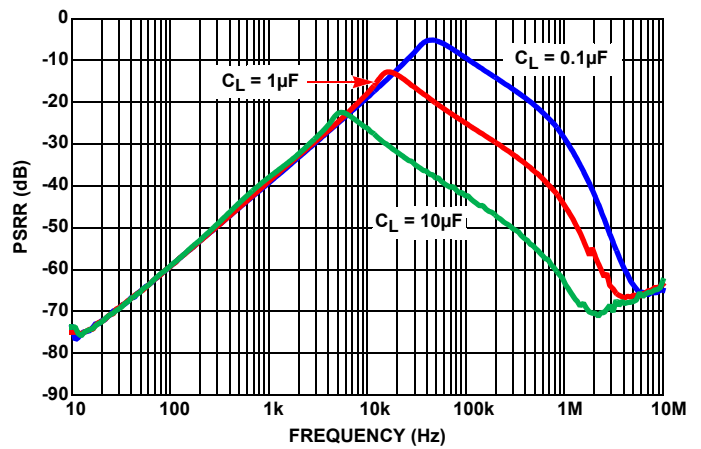


FIGURE 133. RIPPLE REJECTION AT DIFFERENT CAPACITIVE LOADS

Typical Performance Characteristics Curves ($V_{OUT} = 4.096V$) $V_{IN} = 3.0V$,
 $I_{OUT} = 0mA$, $T_A = +25^\circ C$ unless otherwise specified. (Continued)



FIGURE 134. DROPOUT (10mA SOURCED LOAD)

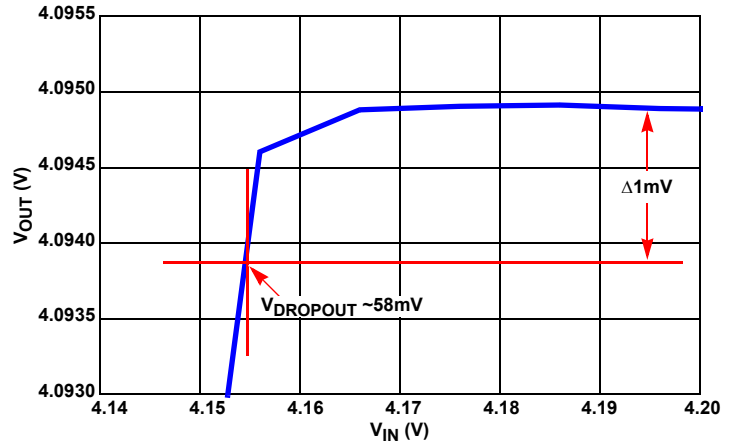


FIGURE 135. DROPOUT ZOOMED (10mA SOURCED LOAD)

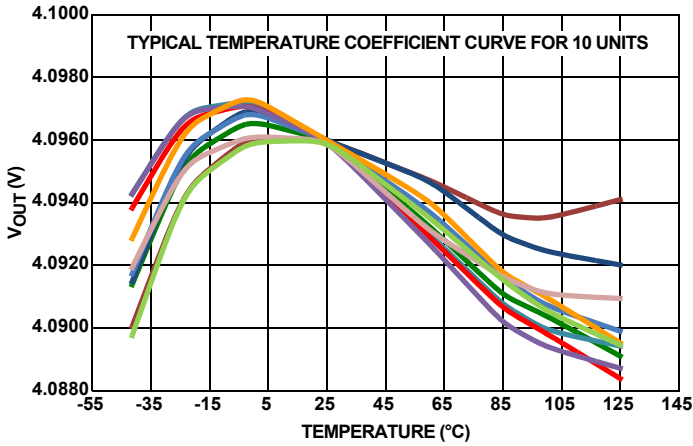


FIGURE 136. V_{OUT} vs TEMPERATURE

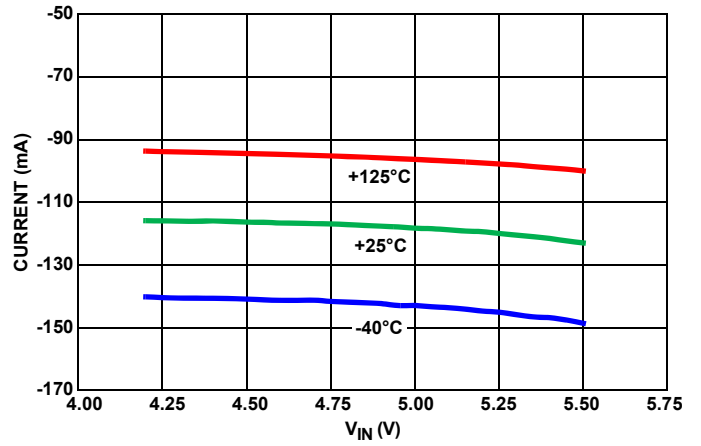


FIGURE 137. SHORT-CIRCUIT TO GND



FIGURE 138. V_{OUT} vs NOISE, 0.1Hz TO 10Hz

Applications Information

Micropower Operation

The ISL21010 consumes very low supply current due to the proprietary bandgap technology. Low noise performance is achieved using optimized biasing techniques. Supply current is typically 48 μ A and noise in the 0.1Hz to 10Hz bandwidth is 58 μ V_{P-P} to 100 μ V_{P-P} (V_{OUT} = 2.048V, 3.0V and 3.3V) benefiting precision, low noise portable applications such as handheld meters and instruments.

Data Converters in particular can use the ISL21010 as an external voltage reference. Low power DAC and ADC circuits will realize maximum resolution with lowest noise. The device maintains output voltage during conversion cycles with fast response, although it is helpful to add an output capacitor, typically 1 μ F.

Board Mounting Considerations

For applications requiring the highest accuracy, the board mounting location should be reviewed. The device uses a plastic SOIC package, which will subject the die to mild stresses when the Printed Circuit Board (PCB) is heated and cooled, slightly changing the shape. Placing the device in areas subject to slight twisting degrades the accuracy of the reference voltage due to these die stresses. It is normally best to place the device near the edge of a board, or the shortest side, as the axis of bending is most limited at that location. Mounting the device in a cutout also minimizes flex. Obviously mounting the device on flexprint or extremely thin PCB material will likewise cause loss of reference accuracy.

Board Assembly Considerations

Bandgap references provide high accuracy and low temperature drift but some PCB assembly precautions are necessary. Normal output voltage shifts of 100 μ V to 4mV can be expected with Pb-free reflow profiles or wave solder on multilayer FR4 PCBs. Avoid excessive heat or extended exposure to high reflow or wave solder temperatures, this may reduce device initial accuracy.

Noise Performance and Reduction

The recommended capacitive load range for the ISL21010 is from 0.1 μ F to 10.0 μ F (0.22 μ F minimum required for 1.024V option) to ensure stability and best transient performance. Parallel 0.1 μ F (0.22 μ F for 1.024V) and 10 μ F capacitors can be used to optimize performance as well. The noise specification stated in the Electrical Specification tables (starting on [page 5](#)) is for 0.1 μ F (0.22 μ F for 1.024V option) capacitive load, and larger values will reduce the output noise level.

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest Rev.

DATE	REVISION	CHANGE
Mar 30, 2018	FN7896.5	Updated Related Literature. Added new parts and updated notes in the Ordering Information table on page4. Removed About Intersil section and updated disclaimer.
Feb 12, 2016	FN7896.4	Removed DAQ on a stick reference from "Related Literature" on page 1. Updated "Ordering Information" on page 4 by adding column for tape and reel option. Updated HBM value to kV (5500V to 5.5kV) in "Absolute Maximum Ratings" on page 5.
Jan 8, 2015	FN7896.3	On page 1, in the Related Literature section added AN1853 and AN1883. On page 4, updated the ordering information table by adding the (-T7A) products. Changed the y-axis units on Figure 19 on page 12 from "(V)" to "(μV)".
Jun 23, 2014	FN7896.2	Added Curves for Voltage Refs 1.25V, 1.024V, 1.5V, 2.5V and 4.096V Updated POD with following changes: In Detail A, changed lead width dimension from 0.13+/-0.05 to 0.085-0.19 Changed dimension of foot of lead from 0.31+/-0.10 to 0.38+/-0.10 In Land Pattern, added 0.4 Rad Typ dimension In Side View, changed height of package from 0.91+/-0.03 to 0.95+/-0.07
Nov 28, 2011	FN7896.1	On page 1, Features: removed "Coming Soon" from ISL21010-10, -12, -15; ISL21010-25; and ISL21010-40 voltage options; combined -20 option with -10, -12, -15; changed -40 to -41 On page 4, Ordering Information: added parts ISL21010DFH310Z-TK, ISL21010DFH312Z-TK, ISL21010CFH315Z-TK, ISL21010CFH325Z-TK, ISL21010CFH341Z-TK On page 5, Recommended Operating Conditions: added VOUT = 1.024V, 1.25V, 1.5V, 2.048V, 2.2V to 5.5V; VOUT = 2.5V.....2.6V to 5.5V; VOUT = 4.096V.....4.2V to 5.5V On page 5 through page 9, added Electrical Specifications tables for (ISL21010-10, VOUT = 1.024V), (ISL21010-12, VOUT = 1.25V), (ISL21010-15, VOUT = 1.5V), (ISL21010-41, VOUT = 4.096V) On page 7, Electrical Specifications (ISL21010-20, VOUT = 2.048V): changed VOUT/ TA, Thermal Hysteresis, TYP from 50 to 100 On page 9, Note 10: changed "... where V _{OUT} drops 1mV from V _{IN} = 5.0V at T _A = +25° C." to "... where V _{OUT} drops 1mV from V _{IN} = nominal at T _A = +25° C." On page 26, Figure 95, changed title from "LOAD REGULATION OVER-TEMPERATURE" to "LOAD TRANSIENT RESPONSE AT 25mA LOAD". Figure 27, changed title from "LOAD TRANSIENT RESPONSE" to "LOAD TRANSIENT RESPONSE AT 1mA LOAD". On page 27, Figure 100, and page 30, Figure 117, changed figure titles to indicate 10mA instead of 1mA source load. On page 29, Figure 112, changed title from LOAD REGULATION OVER-TEMPERATURE" to "LOAD TRANSIENT RESPONSE AT 25mA LOAD". Figure 113, changed title from "LOAD TRANSIENT RESPONSE" to "LOAD TRANSIENT RESPONSE AT 1mA LOAD" On page 34, under "Noise Performance and Reduction", added reference to capacitive load range for 1.024V option.
Aug 9, 2011	FN7896.0	Initial Release

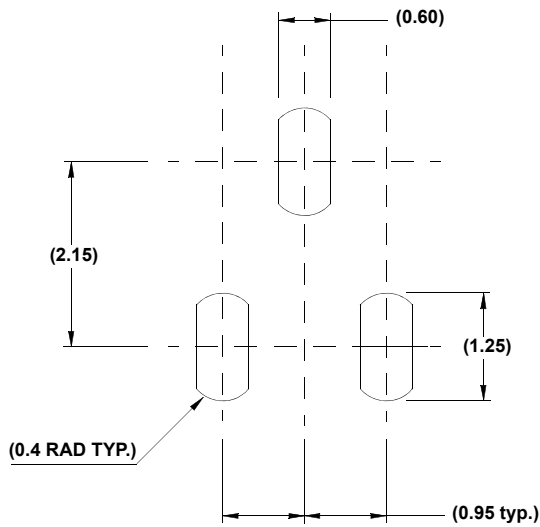
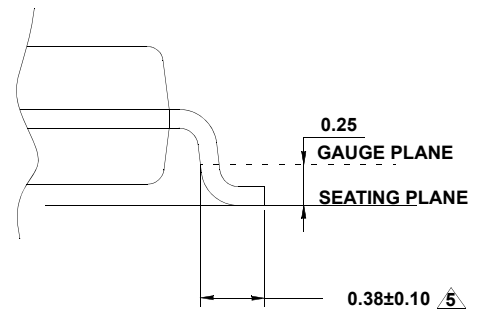
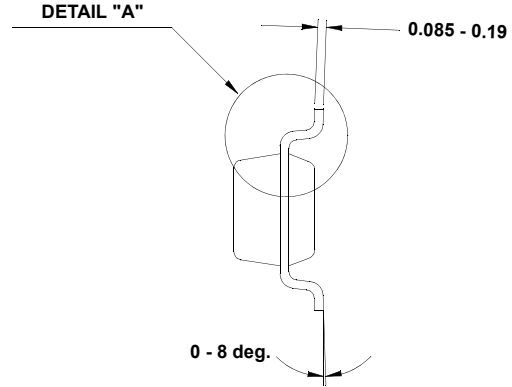
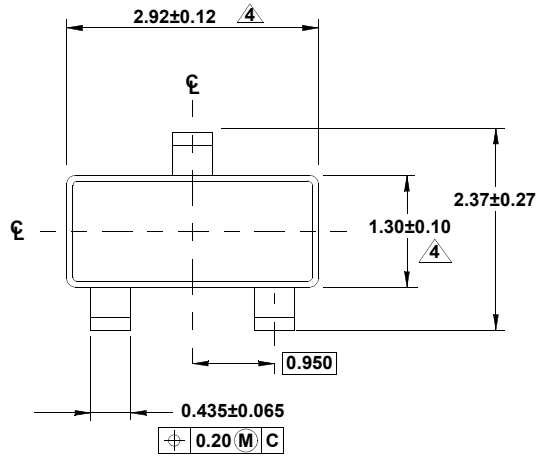
Package Outline Drawing

For the most recent package outline drawing, see [P3.064](#).

P3.064

3 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE (SOT23-3)

Rev 3, 3/12



NOTES:

1. Dimensions are in millimeters. Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to AMSEY14.5m-1994.
3. Reference JEDEC TO-236.
4. Dimension does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25mm per side.
5. Footlength is measured at reference to gauge plane.

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Renesas Electronics America Inc.
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.
Tel: +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3
Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-6688, Fax: +852-2886-9022

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
Tel: +886-2-8175-9600, Fax: +886-2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India
Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd.
17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5338